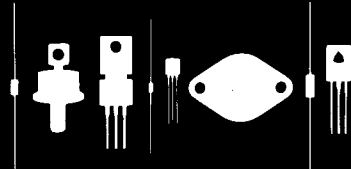


Central  
Semiconductor Corp.

Central  
Semiconductor Corp.

Central™  
Semiconductor Corp.

145 Adams Avenue  
Hauppauge, New York 11788



FAST RECOVERY

HIGH VOLTAGE RECTIFIER

CR250F-X

250mA

1000-6000 VOLTS

AXIAL LEAD EPOXY CASE

DESCRIPTION

The CENTRAL SEMICONDUCTOR CR250F High Voltage Series is a 250mA Axial Lead High Voltage Rectifier designed for general purpose high voltage applications where space limitation is a factor and a fast reverse recovery time is necessary.

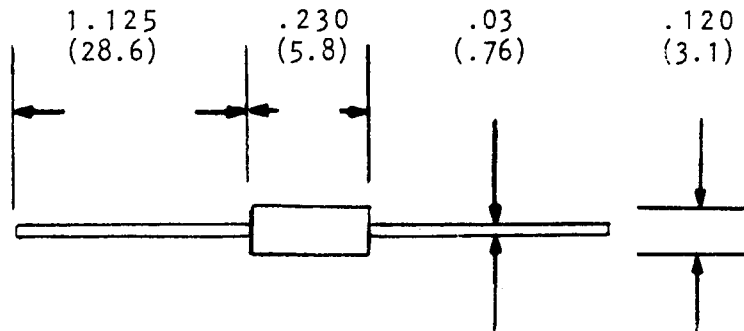
MAXIMUM RATINGS ( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

		CR250F -1	CR250F -2	CR250F -3	CR250F -4	CR250F -5	CR250F -6	UNIT
DC Blocking Voltage	$V_R$	1000	2000	3000	4000	5000	6000	V
Peak Reverse Voltage	$V_{RM}$	1000	2000	3000	4000	5000	6000	V
RMS Reverse Voltage	$V_r$	700	1400	2100	2800	3500	4200	V
Average Forward Current	$I_O$	250	250	250	250	250	250	mA
Peak Forward Current ( $T_A=75^{\circ}\text{C}$ )	$I_{FRM}$	2.0	2.0	2.0	2.0	2.0	2.0	A
Peak Surge Current (Rated $V_R$ , $I_O$ , $T_A=75^{\circ}\text{C}$ , One Cycle)	$I_{FSM}$	20.	20.	20.	20.	20.	20.	A
Operating Junction Temperature	$T_J$			-65 TO +175 $^{\circ}\text{C}$				
Storage Temperature	$T_{stg}$			-65 TO +175 $^{\circ}\text{C}$				

ELECTRICAL CHARACTERISTICS ( $T_A=25^{\circ}\text{C}$  unless otherwise noted)

SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
$I_R$	$V_R$ =Rated		1.0	uA
$I_R$	$V_R$ =Rated, $T_A=100^{\circ}\text{C}$		50	uA
$V_F$	$I_F=0.25\text{A}$ (-1, -2)		3.25	V
$V_F$	$I_F=0.25\text{A}$ (-3, -4)		6.75	V
$V_F$	$I_F=0.25\text{A}$ (-5, -6)		9.25	V
$T_{rr}$			200	ns

OUTLINE DRAWING



Dimensions in inches and (millimeters).

145 Adams Avenue, Hauppauge, NY 11788 USA  
Tel: (631) 435-1110 • Fax: (631) 435-1824